

# Description

The FDD8445 uses advanced trench technology

to provide excellent  $\mathsf{R}_{\mathsf{DS}(\mathsf{ON})},$  low gate charge and

operation with gate voltages as low as 4.5V. This

device is suitable for use as a

Battery protection or in other Switching application.

## **General Features**

V<sub>DS</sub> = 40V I<sub>D</sub> =60A

 $R_{DS(ON)} < 8.5m\Omega @ V_{GS}=10V$ 

# Application

Battery protection

Load switch Uninterruptible power supply

## Package Marking and Ordering Information

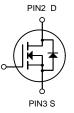
Product ID	Pack	Brand	Qty(PCS)
FDD8445	TO-252-2L	HXY MOSFET	2500

## Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

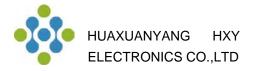
Symbol	Symbol Parameter		Units	
Vds	Drain-Source Voltage	40	V	
Vgs	Gate-Source Voltage	±20	V	
I⊳@Tc=25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	60	А	
I₀@Tc=100°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup> 45		
Ідм	Pulsed Drain Current <sup>2</sup>	Pulsed Drain Current <sup>2</sup> 220		
EAS	Single Pulse Avalanche Energy3416.1		mJ	
las	Avalanche Current	Avalanche Current 39		
P <sub>D</sub> @T <sub>C</sub> =25°C	Total Power Dissipation <sup>4</sup>	64.6	W	
Тѕтс	Storage Temperature Range	-55 to 150	°C	
TJ	Operating Junction Temperature Range	-55 to 150	°C	
Reja	Thermal Resistance Junction-ambient (Steady State) <sup>1</sup>	62	°C/W	
Rejc	Thermal Resistance Junction-Case <sup>1</sup>	ermal Resistance Junction-Case <sup>1</sup> 2.8		







N-Channel MOSFET



# Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics	L					1	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	40	45	-	V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V	-	-	1	μA	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA	
On Characteristics (Note 3)	I		_				
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	1.2	1.6	2.0	V	
Drain Source On State Desistence	P	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	7.0	8.5	- mΩ	
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A		15	18		
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =10V,I <sub>D</sub> =20A		-	-	S	
Dynamic Characteristics (Note4)	·						
Input Capacitance	C <sub>lss</sub>	N 00)()/ 0)/	-	1800	-	PF	
Output Capacitance	C <sub>oss</sub>	$V_{DS}=20V, V_{GS}=0V,$	-	280	-	PF	
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	190	-	PF	
Switching Characteristics (Note 4)	I		-				
Turn-on Delay Time	t <sub>d(on)</sub>		-	6.4	-	nS	
Turn-on Rise Time	tr	- V <sub>DD</sub> =20V,I <sub>D</sub> =2A,R <sub>L</sub> =1Ω	-	17.2	-	nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>GS</sub> =10V,R <sub>G</sub> =3Ω	-	29.6	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	16.8	-	nS	
Total Gate Charge	Qg	N/ 001/1 00A	-	29		nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=20V,I_{D}=20A,$	-	4.5		nC	
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	6.4		nC	
Drain-Source Diode Characteristics	L					1	
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =10A	-		1.2	V	
Diode Forward Current (Note 2)	Is		-	-	68	Α	
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 20A	-	29	-	nS	
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	26	-	nC	
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)					

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.

**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production

**5.**  $E_{AS}$  condition : Tj=25°C,  $V_{DD}$ =20V,  $V_{G}$ =10V, L=1mH, Rg=25 $\Omega$ ,



V<sub>GS</sub>=10V

I<sub>D</sub>=20A

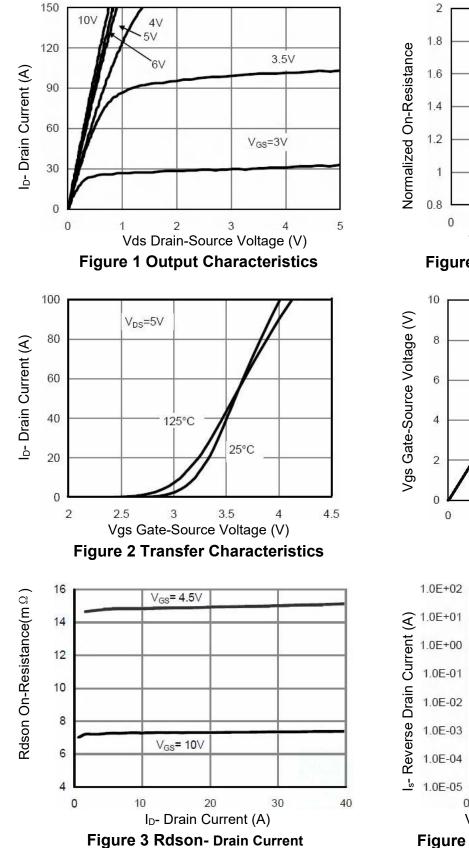
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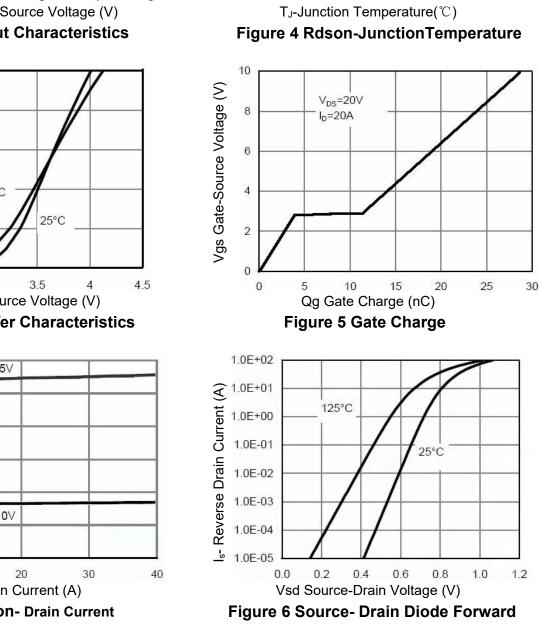
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100 125 150 175

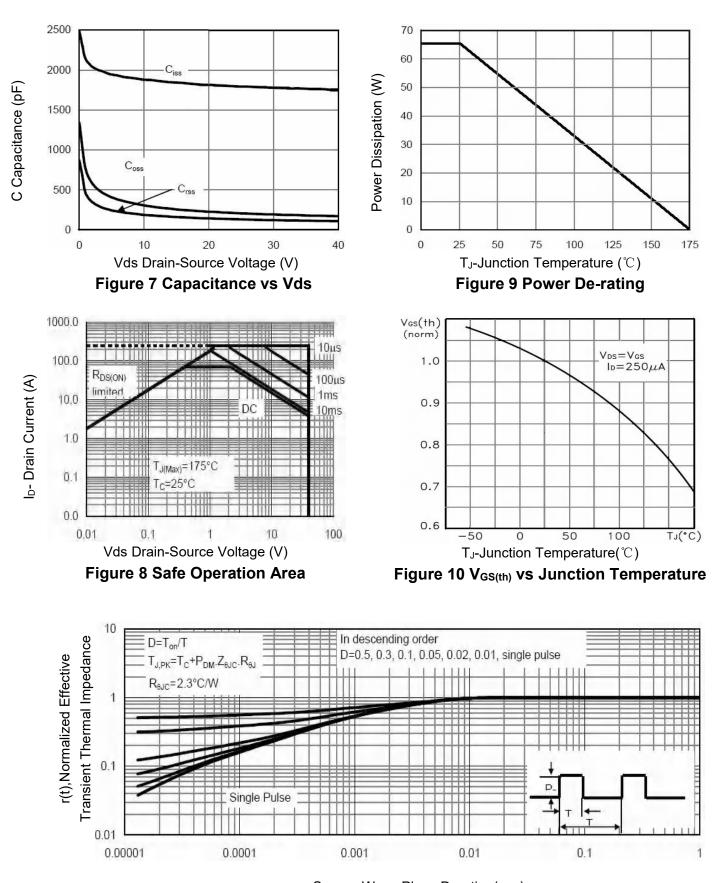
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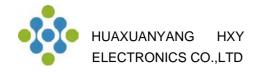
# **Typical Electrical and Thermal Characteristics (Curves)**



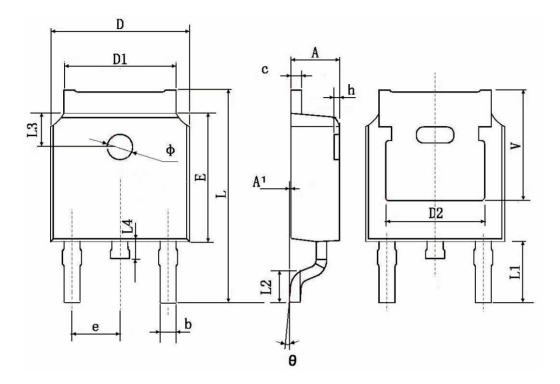




Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance



# TO-252-2L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
с	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483	3 TYP. 0.190 TYP.		TYP.	
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	2.900 TYP.		0.114 TYP.	
L2	1.400	1.700	0.055	0.067	
L3	1.600	TYP.	0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0 °	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	TYP.	0.211 TYP.		



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